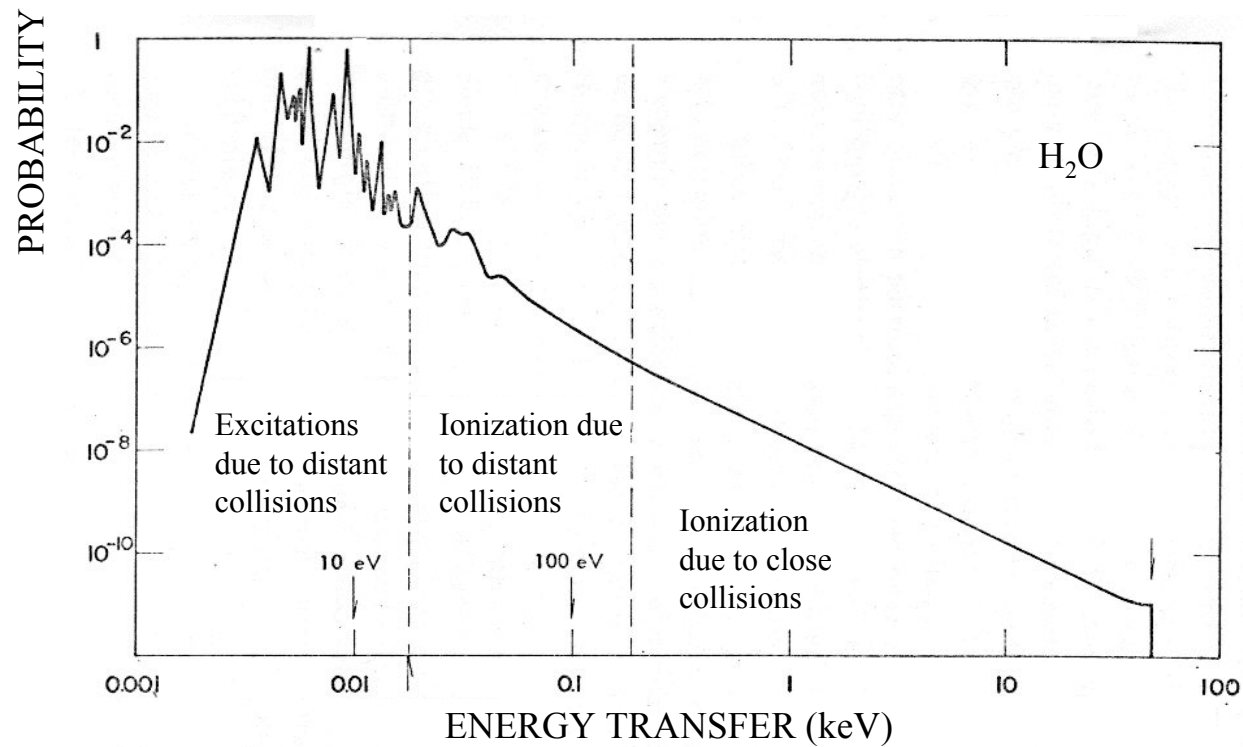


2

INTERACTIONS OF RADIATION WITH MATTER

PROBABILITY OF PRIMARY ELECTROMAGNETIC INTERACTION WITH MATTER



BETHE-BLOCH EXPRESSION

$$-\frac{dE}{dx} = 2\pi N_a r_e^2 m_e c^2 \rho \frac{Z}{A} \frac{z^2}{\beta^2} \left[\ln \left(\frac{2m_e \gamma^2 v^2 W_{MAX}}{I^2} \right) - 2\beta^2 - \delta - 2\frac{C}{Z} \right]$$

r_e : classic electron radius $2.817 \cdot 10^{-13} \text{cm}$

m_e : electron mass

N_a : Avogadro number $6.022 \cdot 10^{23} \text{ mol}^{-1}$

I : average ionization potential

Z, A : atomic number and mass of target

ρ : target density

z : particle charge in units of e

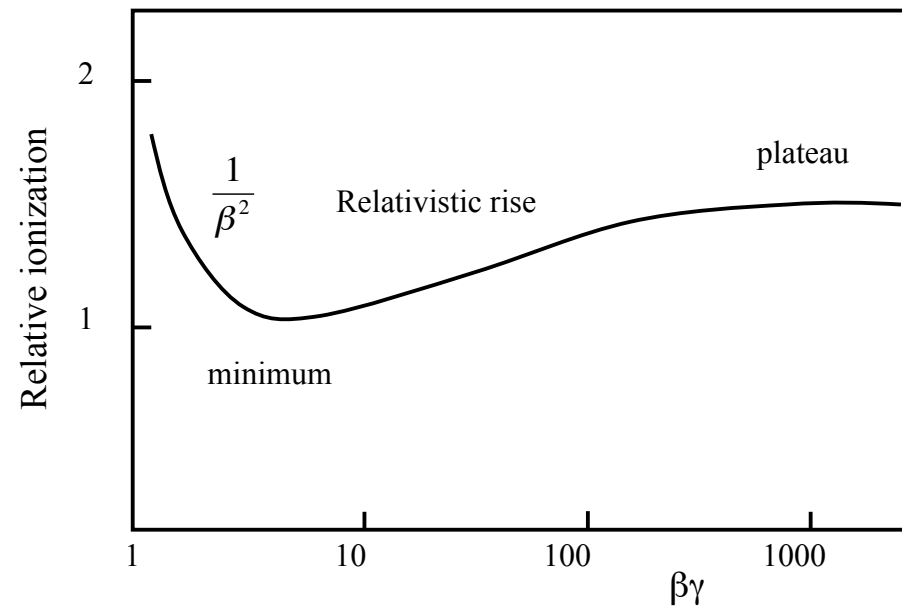
β : v/c of particle

γ : $1/\sqrt{1-\beta^2}$

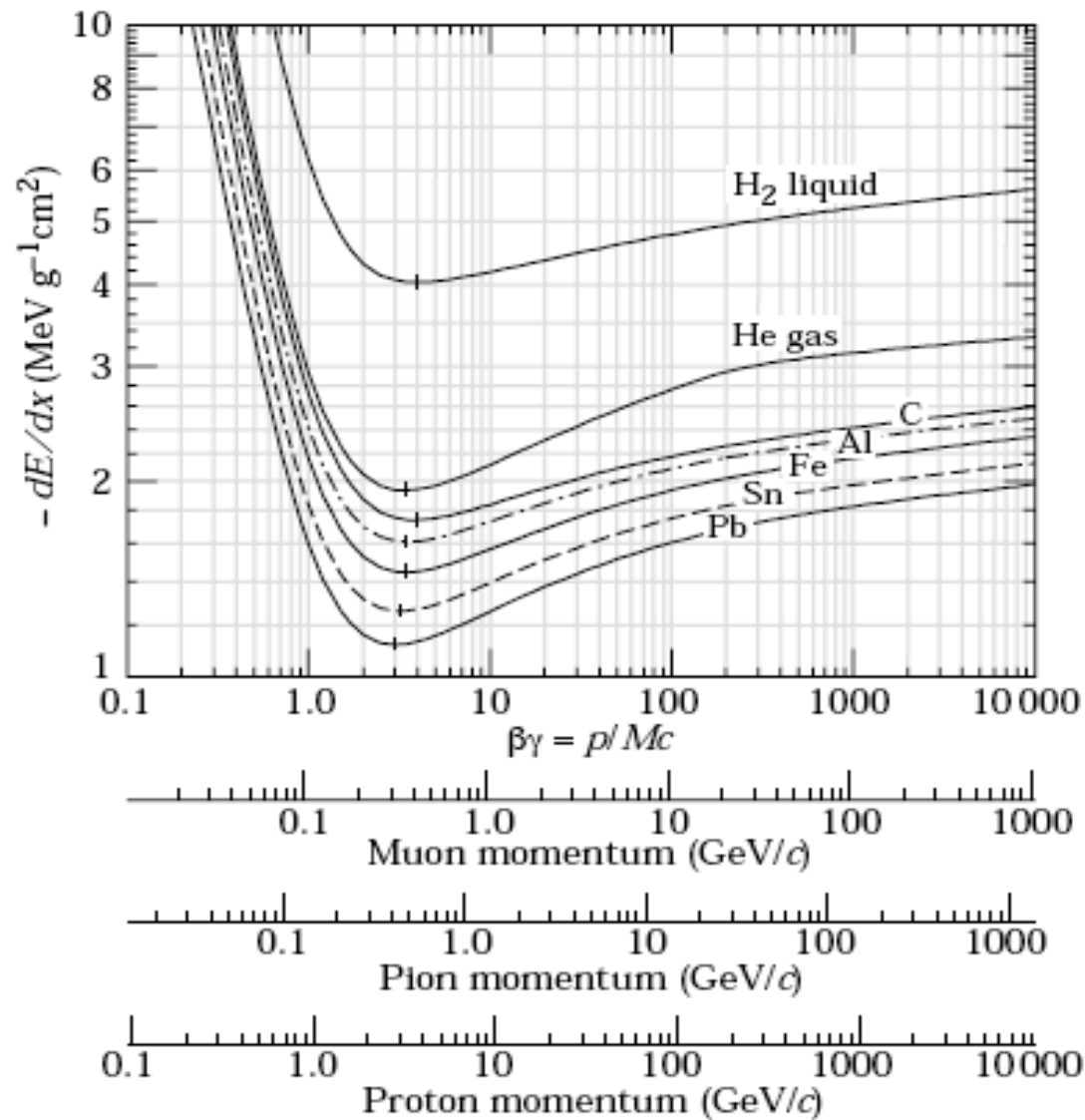
δ : density correction

C : shell correction

W_{MAX} : maximum energy transfer in a collision



$z=1$ particles



Reduced units:

$$\frac{dE}{d\chi} = \frac{1}{\rho} \frac{dE}{dx} \quad \rho: \text{density}$$

$$\chi(\text{g cm}^{-2}) = \rho(\text{g cm}^{-3}) l(\text{cm})$$

In composite materials:

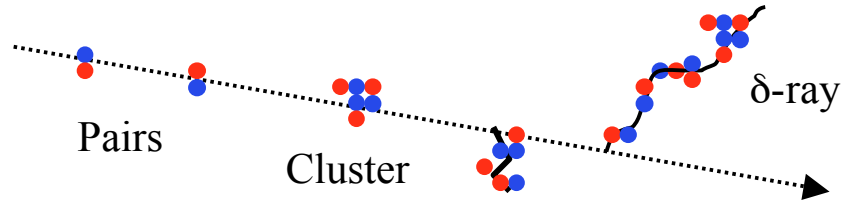
$$\frac{dE}{dx} = \sum p_i \left| \frac{dE}{dx} \right|_i$$

p_i : fraction of material i

*Review of Particle Physics,
Physics Letters B667 (2008) 1*

<http://pdg.lbl.gov/>

CREATION OF ELECTRON-ION PAIRS



Primary ionization probability:

$$P_k^n = \frac{n^k}{k!} e^{-n}$$

k: actual number
n: average

Total ionization probability (Landau expression):

$$f(\lambda) = \frac{1}{\sqrt{2\pi}} e^{-\frac{1}{2}(\lambda + e^{-\lambda})}$$

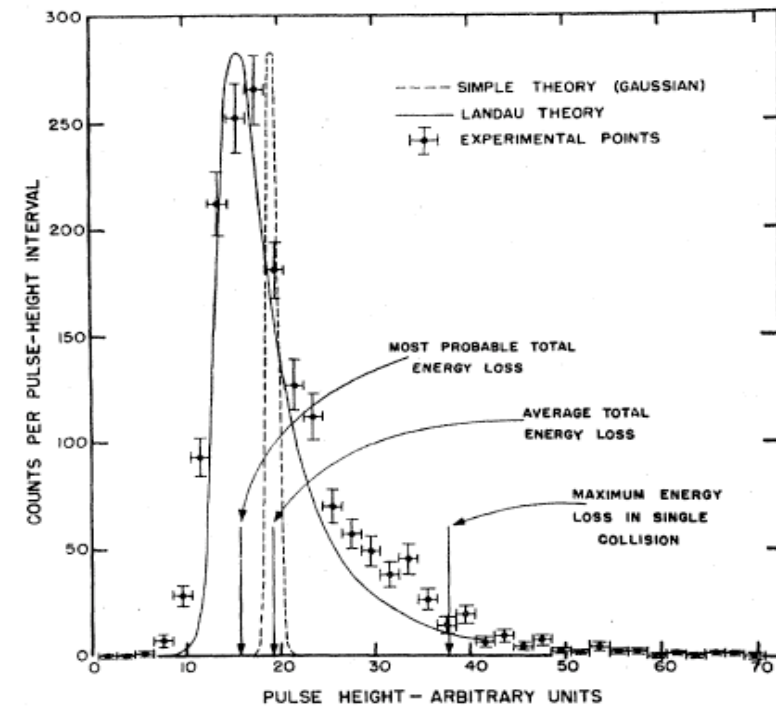
$$\lambda = \frac{\Delta E - \Delta E_{MP}}{\xi} \quad \xi = K \frac{Z}{A} \frac{\rho}{\beta^2} x$$

Average total ionization:

$$N = \frac{\Delta E}{W_i}$$

ΔE : energy loss
 W_i : average energy per ion pair

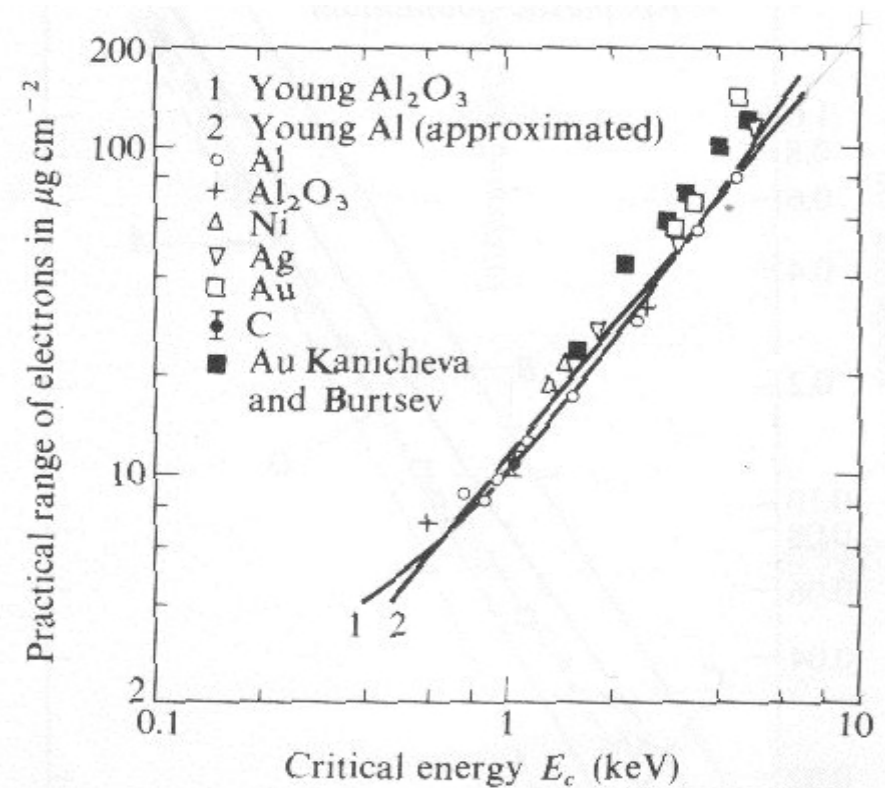
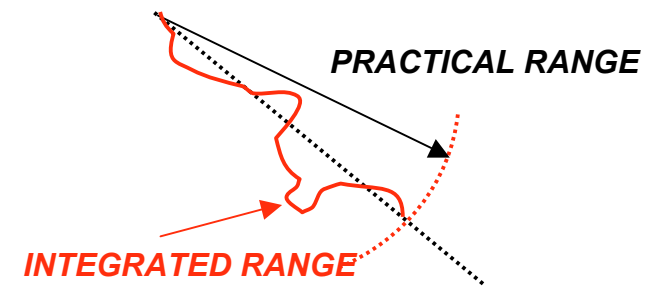
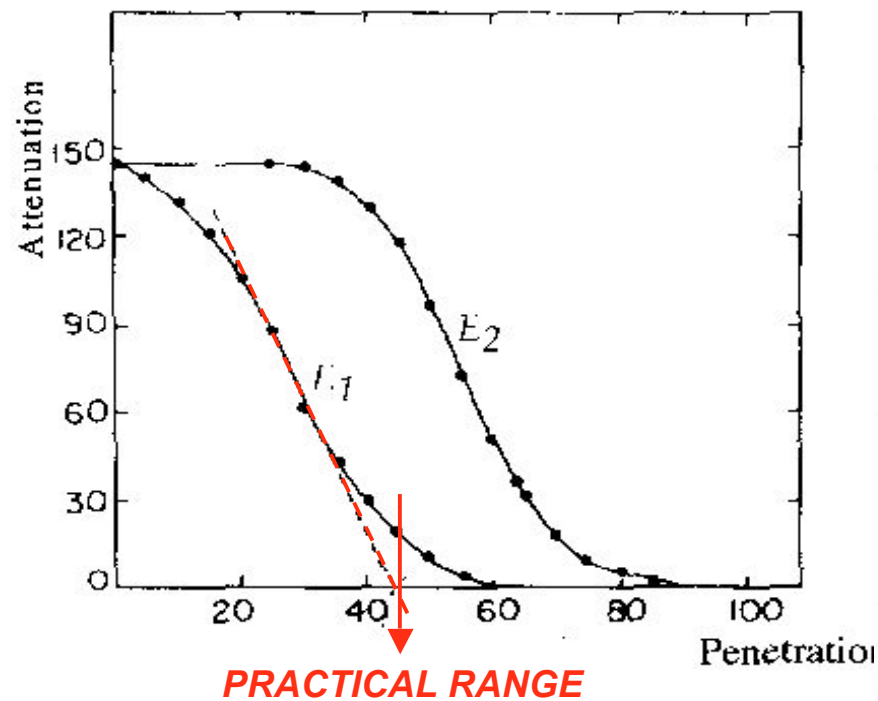
TOTAL IONIZATION ENERGY LOSS



G. Igo et al, Phys. Rev. 89(1953)879

PATH IN MATERIALS OF DELTA ELECTRONS

Dispersed by multiple scattering



H. Kanter, *Phys. Rev.* 121(1961)461

ENERGY LOSS IN SEMICONDUCTORS (MINIMUM IONIZING PARTICLES)

MATERIAL	Z	ρ (g cm ⁻³)	W_i (eV)	dE/dx (MeV g ⁻¹ cm ²)	dE/dx (MeV cm ⁻¹)
Silicon	14	2.34	3.6	1.6	3.7
Germanium	32	5.32	2.96	1.4	7.5

Z : charge ρ : density W_i average ionization energy

Average number of ion pairs:

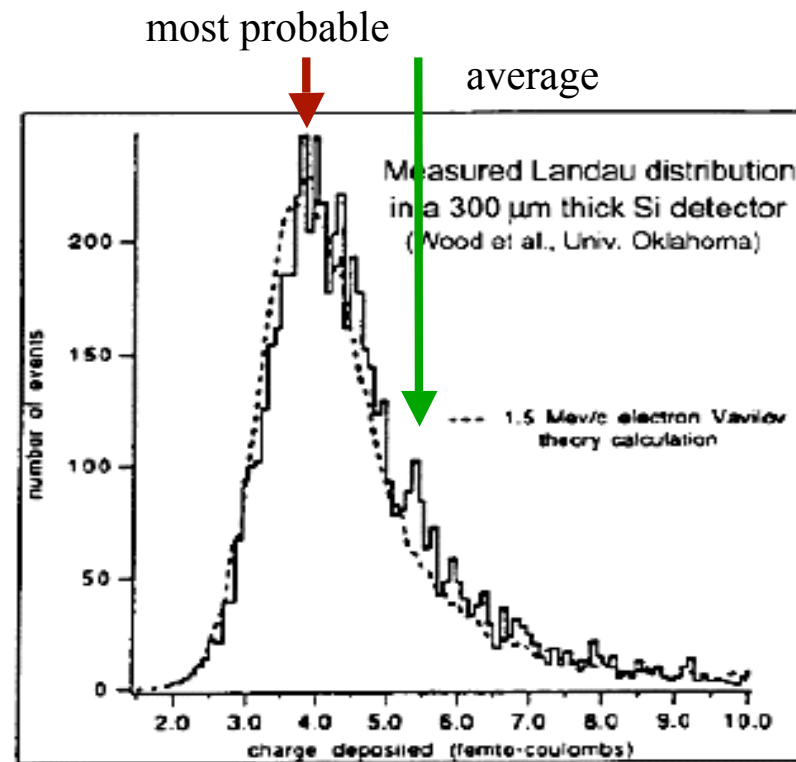
$$n = \frac{\Delta E}{W_i} = \frac{dE/dx}{W_i} s$$

For silicon, 300 μ m thick:

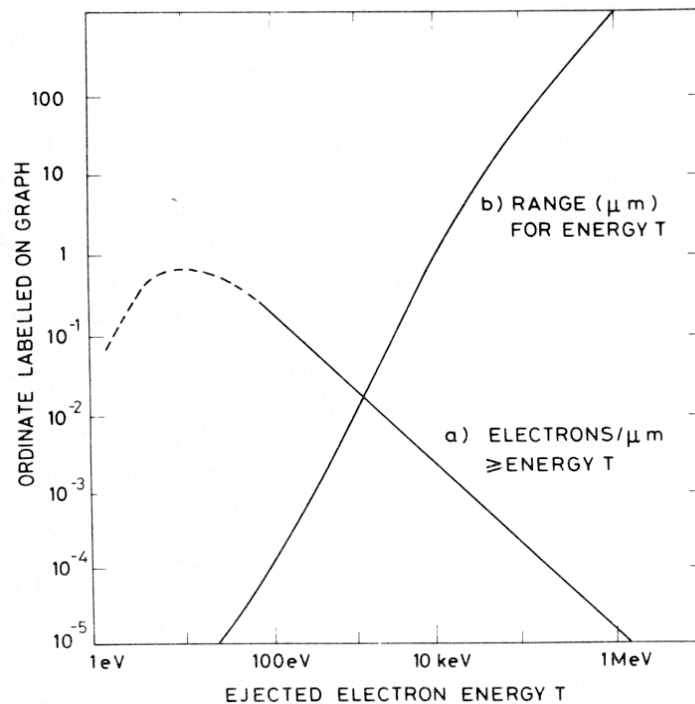
$n \sim 30,000$ electron-hole pairs

or

$$\Delta q = n \times 1.6 \times 10^{-19} \text{ C} = 4.8 \text{ fC}$$

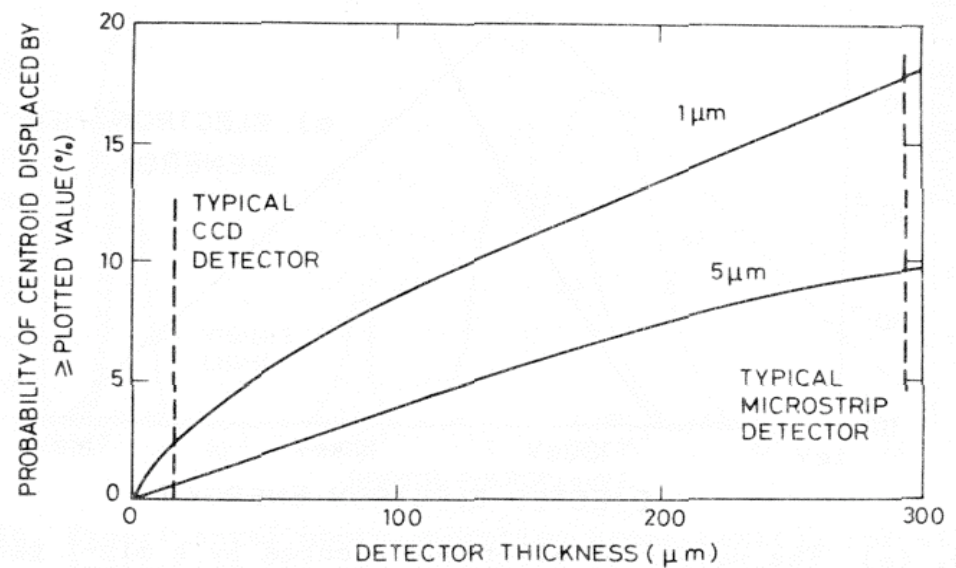


DELTA ELECTRON PRODUCTION PROBABILITY AND RANGE IN SILICON



C. Damerell, RAL 86-77(1986)

POSITION ERROR AS A FUNCTION OF THICKNESS IN SILICON DETECTORS (PERPENDICULAR MIPS)



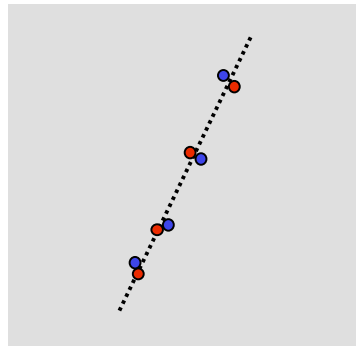
C. Damerell, Nucl. Instr. and Meth. 226(1984)26

MAIN PARAMETERS:

C. Amsler et al,
Review of Particle Physics
Physics Letters B667 (2008) 1

Gas	Density, mg cm ⁻³	E_x eV	E_I eV	W_I eV	$dE/dx _{\min}$ keV cm ⁻¹	N_P cm ⁻¹	N_T cm ⁻¹
Ne	0.839	16.7	21.6	30	1.45	13	50
Ar	1.66	11.6	15.7	25	2.53	25	106
Xe	5.495	8.4	12.1	22	6.87	41	312
CH ₄	0.667	8.8	12.6	30	1.61	37	54
C ₂ H ₆	1.26	8.2	11.5	26	2.91	48	112
iC ₄ H ₁₀	2.49	6.5	10.6	26	5.67	90	220
CO ₂	1.84	7.0	13.8	34	3.35	35	100
CF ₄	3.78	10.0	16.0	54	6.38	63	120

PRIMARY IONIZATION:



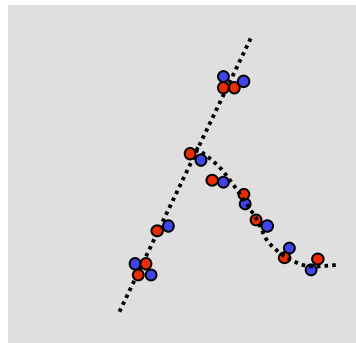
Minimum ionizing particles in Argon NTP:

$$dE/dx: 2.4 \text{ keV/cm} \quad n_p: 25 \text{ ion pairs/cm}$$

Detection efficiency: $\varepsilon = 1 - P_0^n = 1 - e^{-n}$

Thickness:	s (mm)	ε (%)
	1	91.8
	2	99.3

TOTAL IONIZATION:

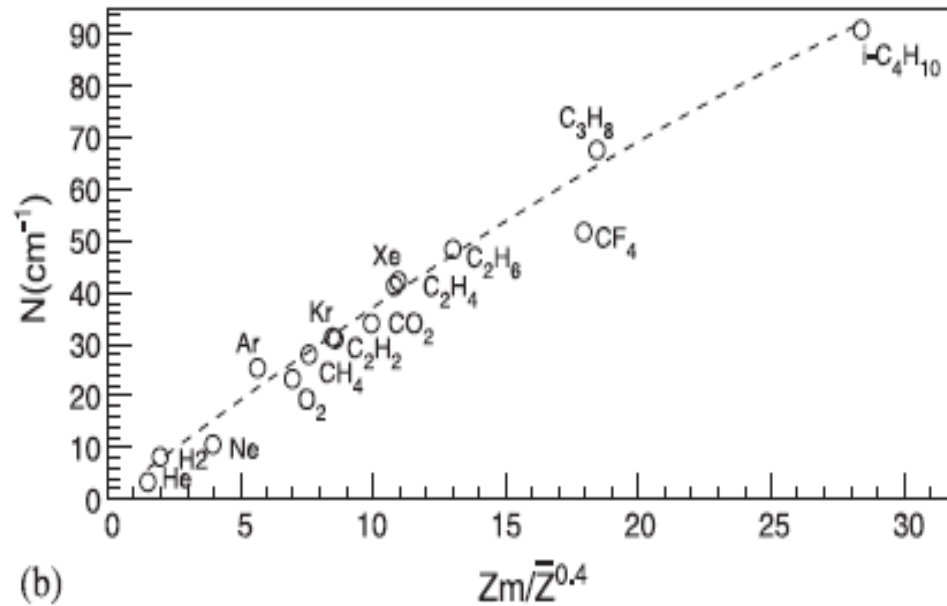


Total number of ion pairs: $n_T = \frac{\Delta E}{W_i}$

$$\Delta E = 2.4 \text{ keV/cm} \quad w_i = 26 \text{ eV} \quad n_T \approx 90 \text{ ip/cm}$$

$$\frac{n_T}{n_P} \approx 3$$

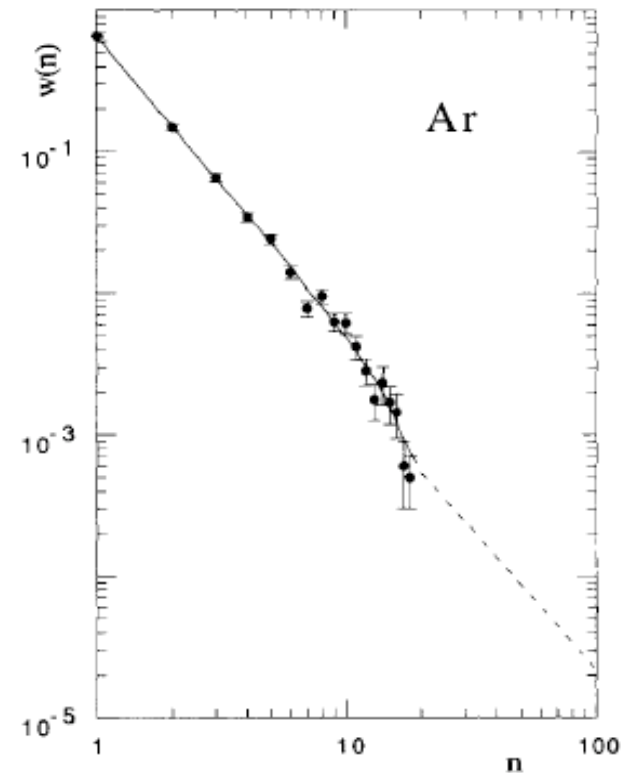
PROGRAM HEED:
NUMBER OF PRIMARY INTERACTIONS
(CLUSTERS) IN GASES AT STP



I. B. Smirnov, Nucl. Instr. and Meth. A554(2005)474

<http://consult.cern.ch/writeup/heed/>

EXPERIMENTAL CLUSTER SIZE
PROBABILITY:



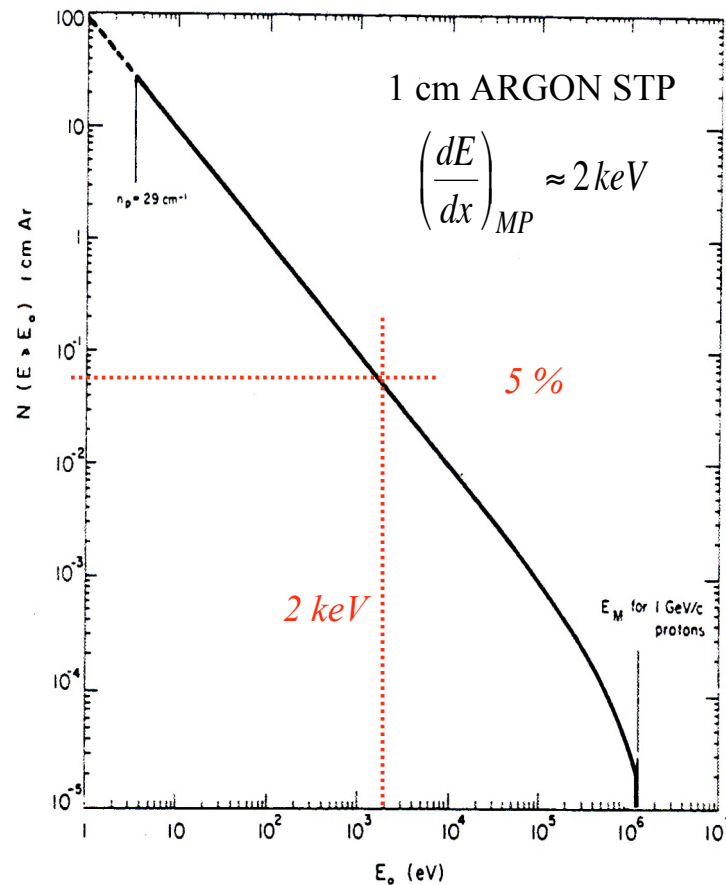
H. Fischle et al, Nucl. Instr. and Meth. A301 (1991) 202

APPROXIMATE EXPRESSIONS

Number of electrons with energy larger than E_0 :
(first term of Bethe-Block)

$$N(E \geq E_0) \approx \frac{W}{E_0} \quad W = K \frac{Z}{A} \rho x$$

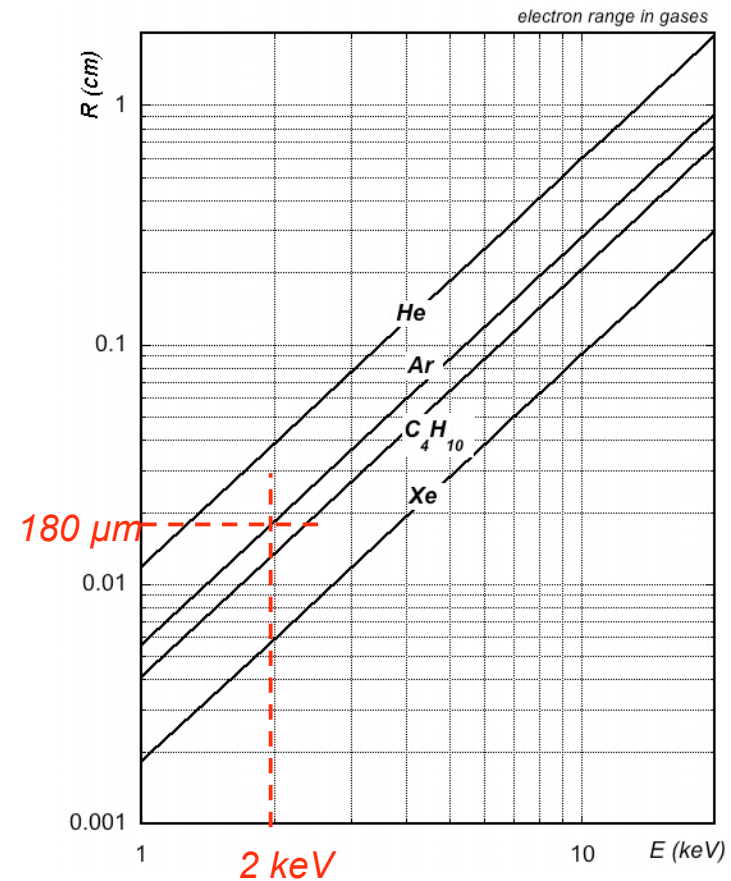
$K = 0.154 \text{ MeV cm}^2/\text{g}$
 ρ : density (g/cm^3)
 x : material thickness (cm)



ELECTRON RANGE IN GASES AT STP:

$$R \approx \frac{1}{\rho} 10 E^{1.7}$$

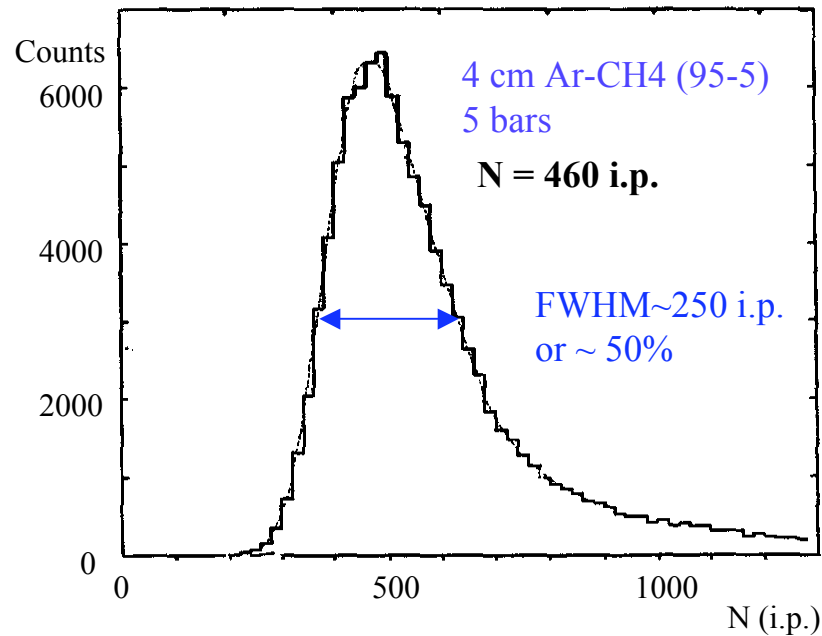
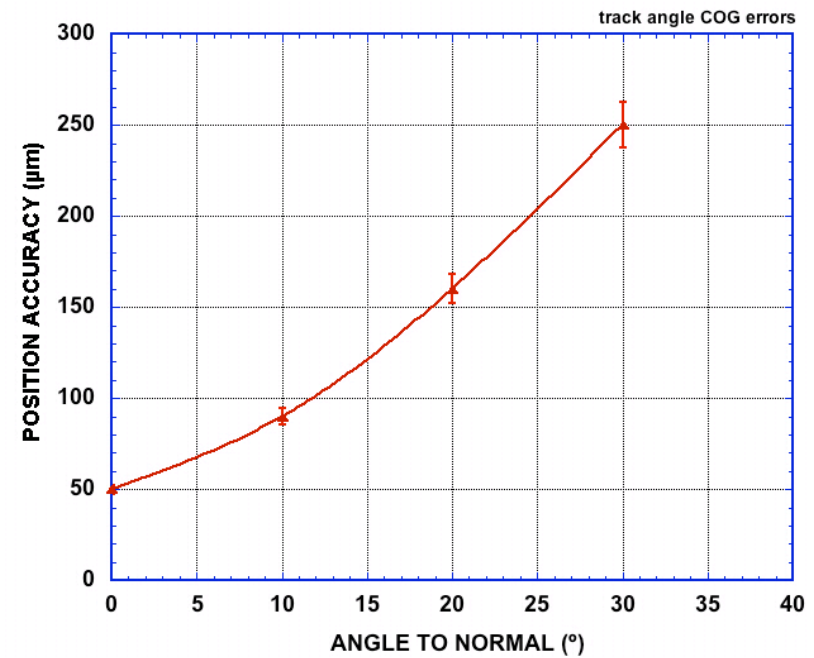
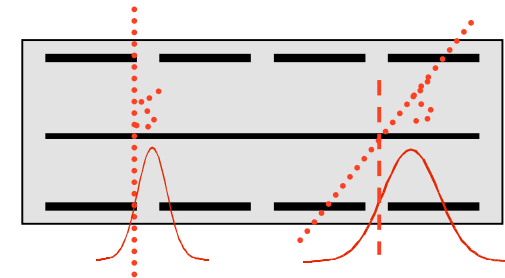
R : range in cm
 E : electron energy in keV
 ρ : density in $\mu\text{g cm}^{-3}$



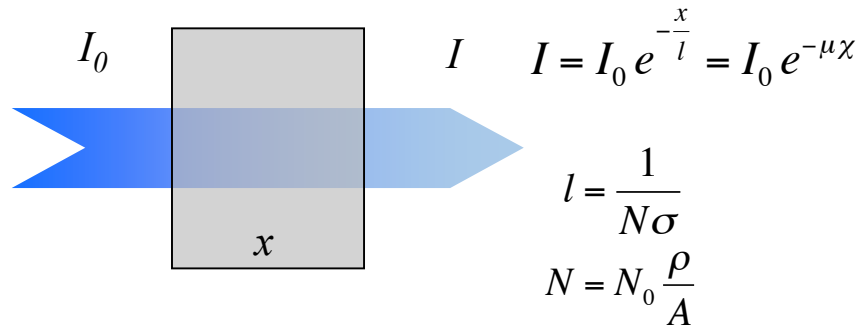
F. Sauli, Nucl. Instr. and Meth. 156 (1978) 147

CONSEQUENCES OF DELTA ELECTRON STATISTICS

DIFFERENTIAL ENERGY LOSS RESOLUTION:

*I. Lehrs et al, Phys. Scripta 23(1981)727*POSITION ACCURACY
(CENTER OF GRAVITY) :*G. Charpak et al, Nucl. Instr. and Meth. 167 (1979) 455*

PHOTON ABSORPTION



x : material thickness (cm)

l : linear absorption length (cm)

$\chi = x \rho$: reduced thickness (g cm^{-2})

$\mu = 1/(l \rho)$: mass absorption coefficient ($\text{cm}^2 \text{g}^{-1}$)

σ : cross section (cm^2)

N : molecules cm^{-3}

$N_0 = 6.0247 \cdot 10^{23}$ molecules/gmole

A : atomic or molecular mass

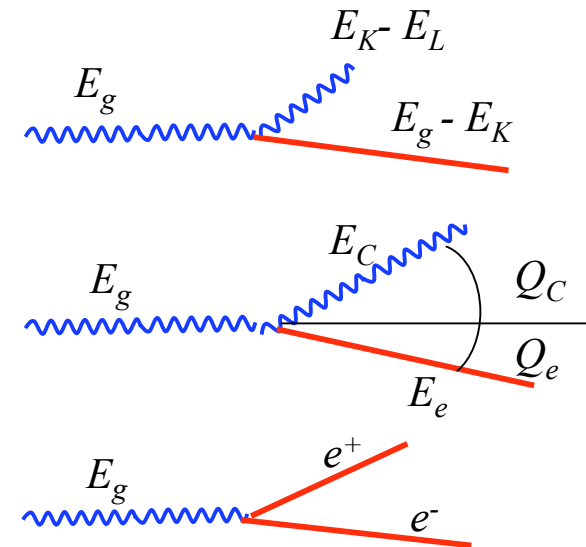
ρ : density (g cm^{-3})

INTERACTION PROCESSES

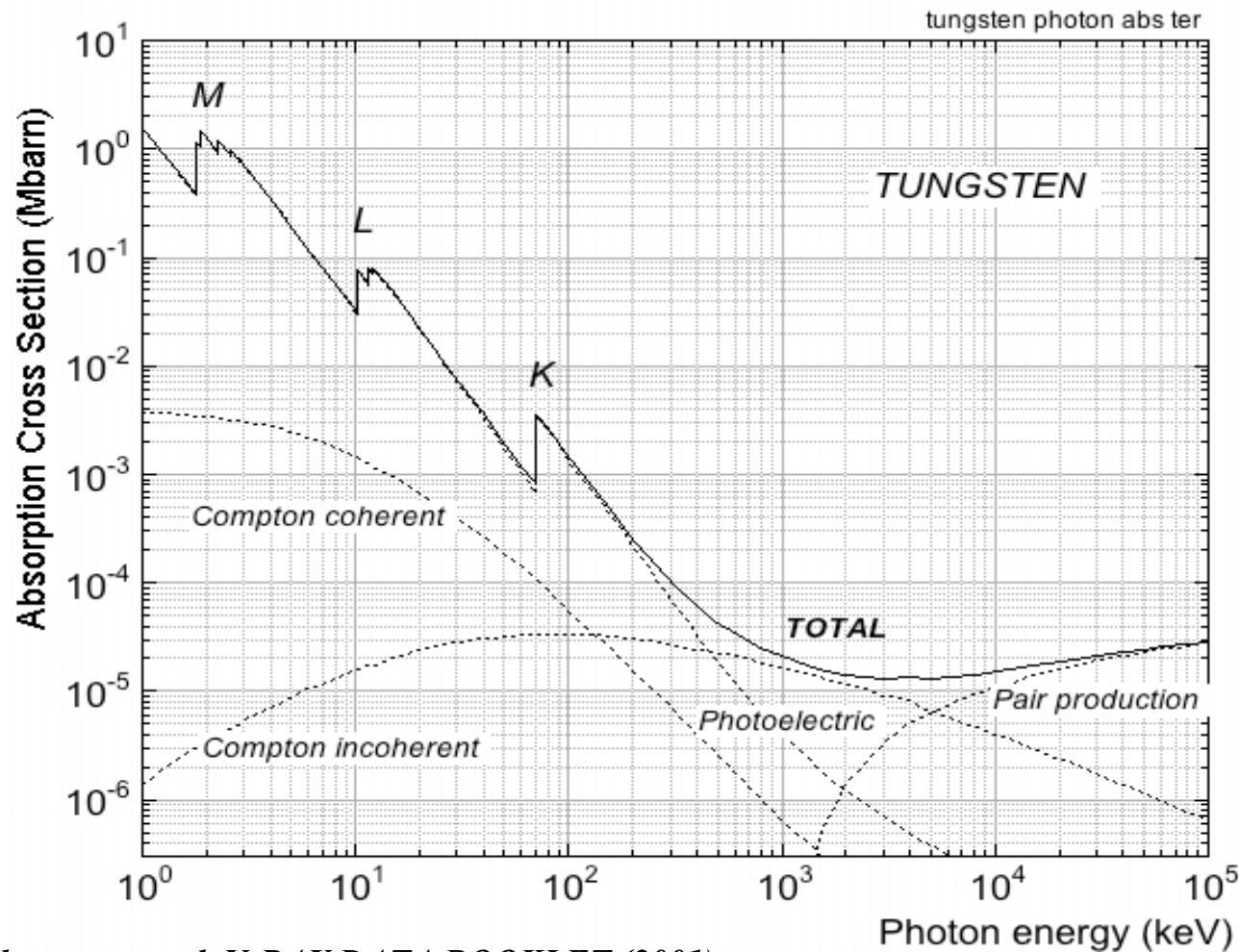
PHOTOELECTRIC: Interaction with an electronic shell with emission of a photoelectron. The excited atom/molecule returns to ground state through fluorescence or radiation-less (Auger) process.

COMPTON: Scattering of the photon by quasi-free electrons; can be coherent or incoherent

PAIR PRODUCTION: Conversion in a e^+e^- pair in the field of the atom/molecule. Possible for $E_g > 2 m_e = 1.022$ MeV



PHOTON ABSORPTION CROSS SECTION FOR TUNGSTEN



A. Thompson et al, X-RAY DATA BOOKLET (2001)

<http://xdb.lbl.gov/>

Absorption tables for atoms and molecules:

http://henke.lbl.gov/optical_constants/

<http://physics.nist.gov/PhysRefData/FFast/html/form.html>

PHOTOELECTRIC EFFECT

WORK FUNCTION:

Minimum photon energy required to remove an electron from a solid (lower than the first ionization potential)

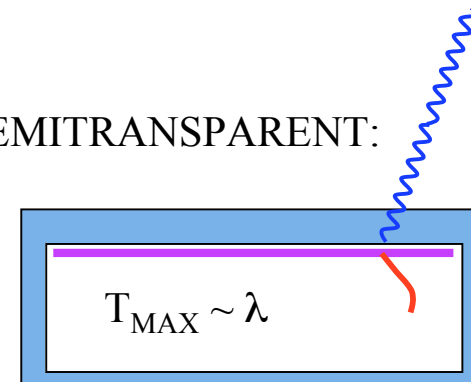
Element	W (eV)	I (eV)
Ag	4.52-4.74	7.57
Au	5.1-5.47	9.22
Al	4.06-4.26	5.99
Fe	4.67-4.81	7.87
Na	2.36	5.14
Li	2.93	5.39
Cs	2.14	3.89

PHOTOIONIZATION THRESHOLD AND QUANTUM EFFICIENCY OF MULTIALKALI

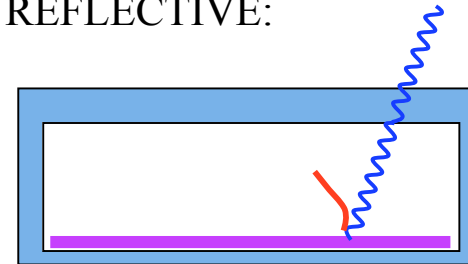
Compound	W (eV)	Max QE (%)
SbCs	1.8	16
SbNaKCs	1.45	20
SbKCs	1.98	26

ELECTRON EMISSION FROM PHOTOCATHODES (IN VACUUM)

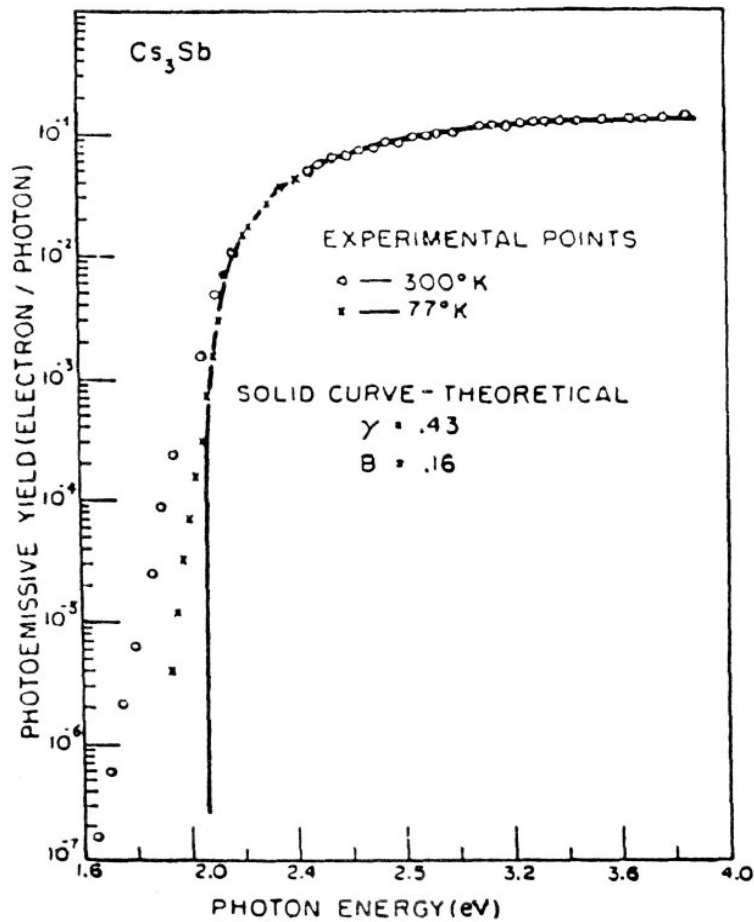
SEMITRANSSPARENT:



REFLECTIVE:



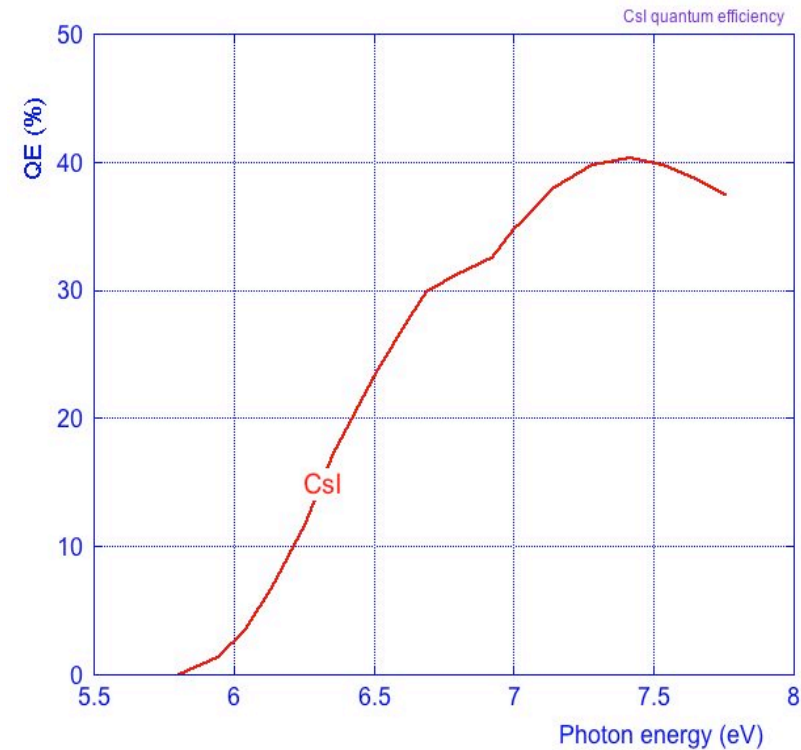
ALKALI PHOTOCATHODES (VISIBLE LIGHT)

QUANTUM EFFICIENCY OF Cs_3Sb 

W. E. Spicer, *Phys. Rev.* 112(1958)114

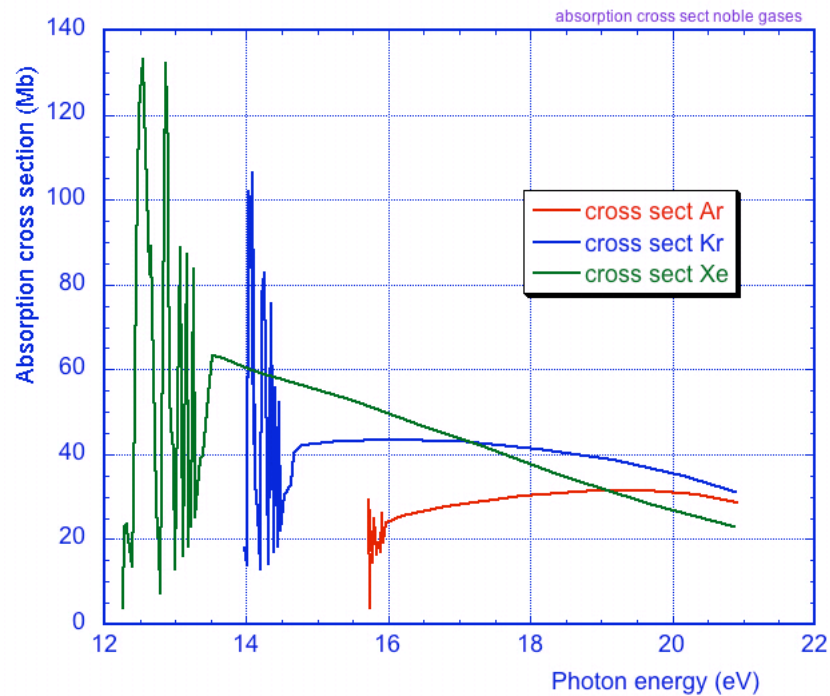
UV PHOTONS

CAESIUM IODIDE QUANTUM EFFICIENCY



CHERENKOV RING IMAGING

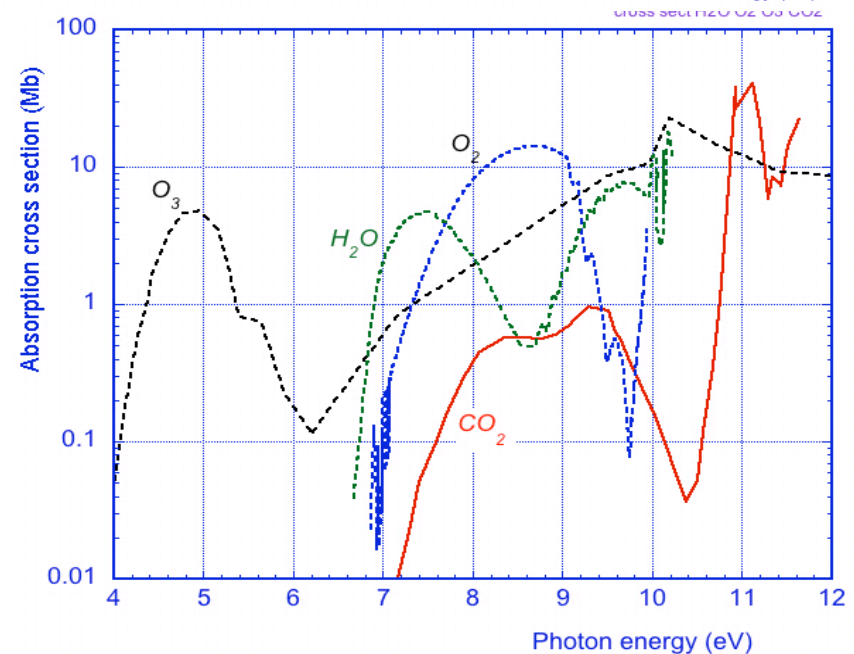
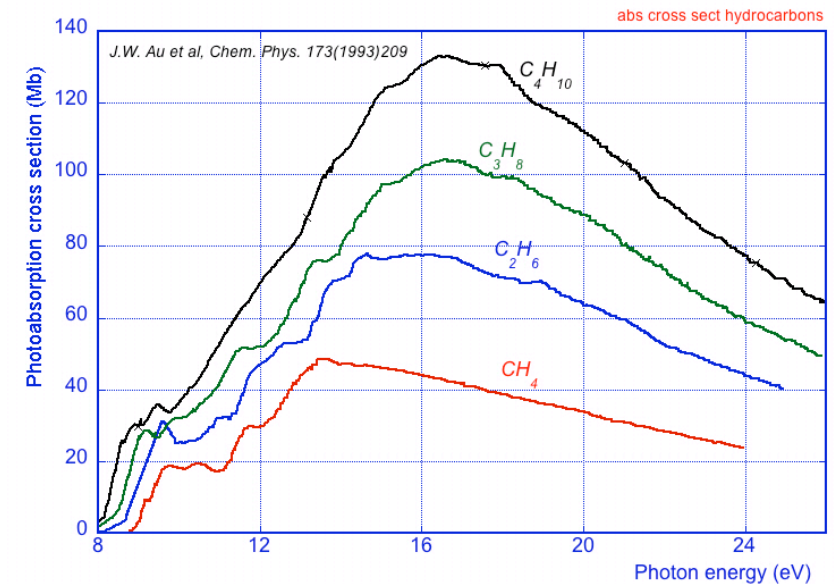
ATOMIC GASES:



H. S. W. Massey, Electronic and Ionic impact Phenomena (Oxford Press 1969)

G. Marr, Photoionization Processes in Gases (Academic Press NY 1967)

MOLECULAR GASES:



PHOTOIONIZATION IN GASES

For a photon energy E_γ above the photoionization threshold E_I the absorption can result in the emission of a photoelectron with energy equal to the difference:

$$E_e = E_\gamma - E_I$$

The quantum efficiency (QE) is the ratio between the probability of photoelectron emission and total absorption.

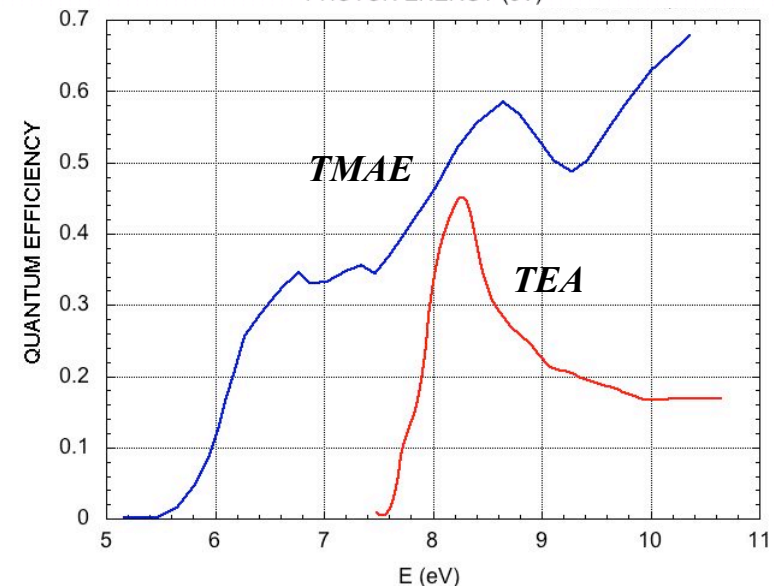
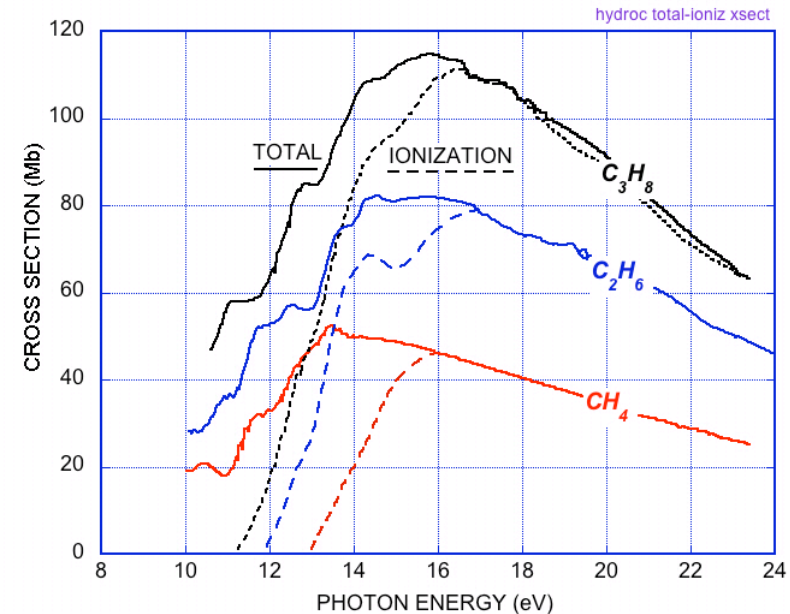
	E_I (eV)
C_6H_6	9.3
TEA	7.45
TMAE	5.6

TEA: Triethylamine $(C_2H_5)_3N$

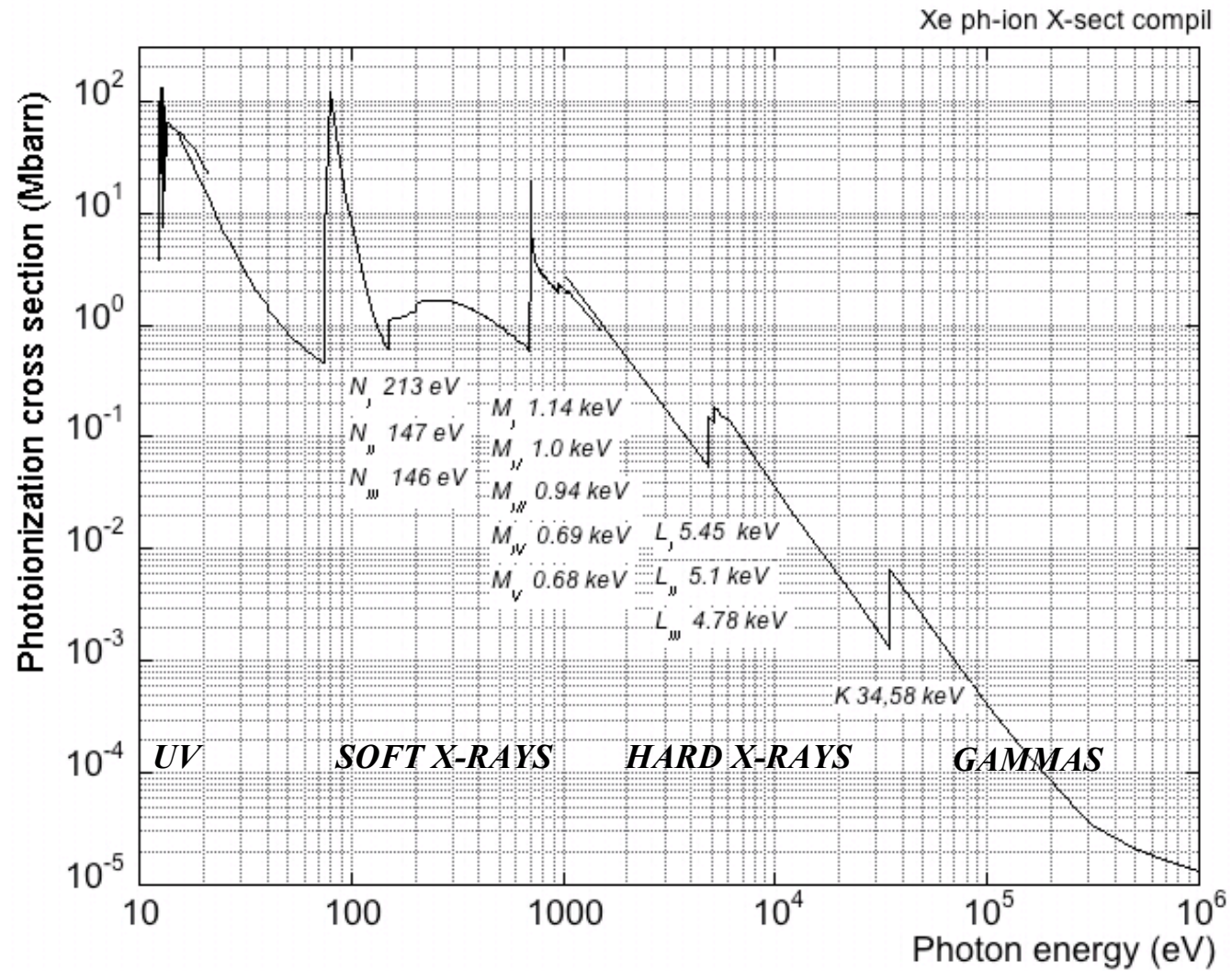
TMAE: Tetrakis-dimethylamino ethylene
 $[(CH_3)_2N]_2C$

➡ CHERENKOV RING IMAGING

TOTAL AND PHOTOIONIZATION CROSS SECTIONS:



PHOTOIONIZATION CROSS SECTION IN XENON



ABSORPTION LENGTH FOR GASES AT NTP

For gases at STP (0°C, 1 Atm):

$$N = 2.687 \cdot 10^{19} \text{ cm}^{-3}$$

Absorption length:

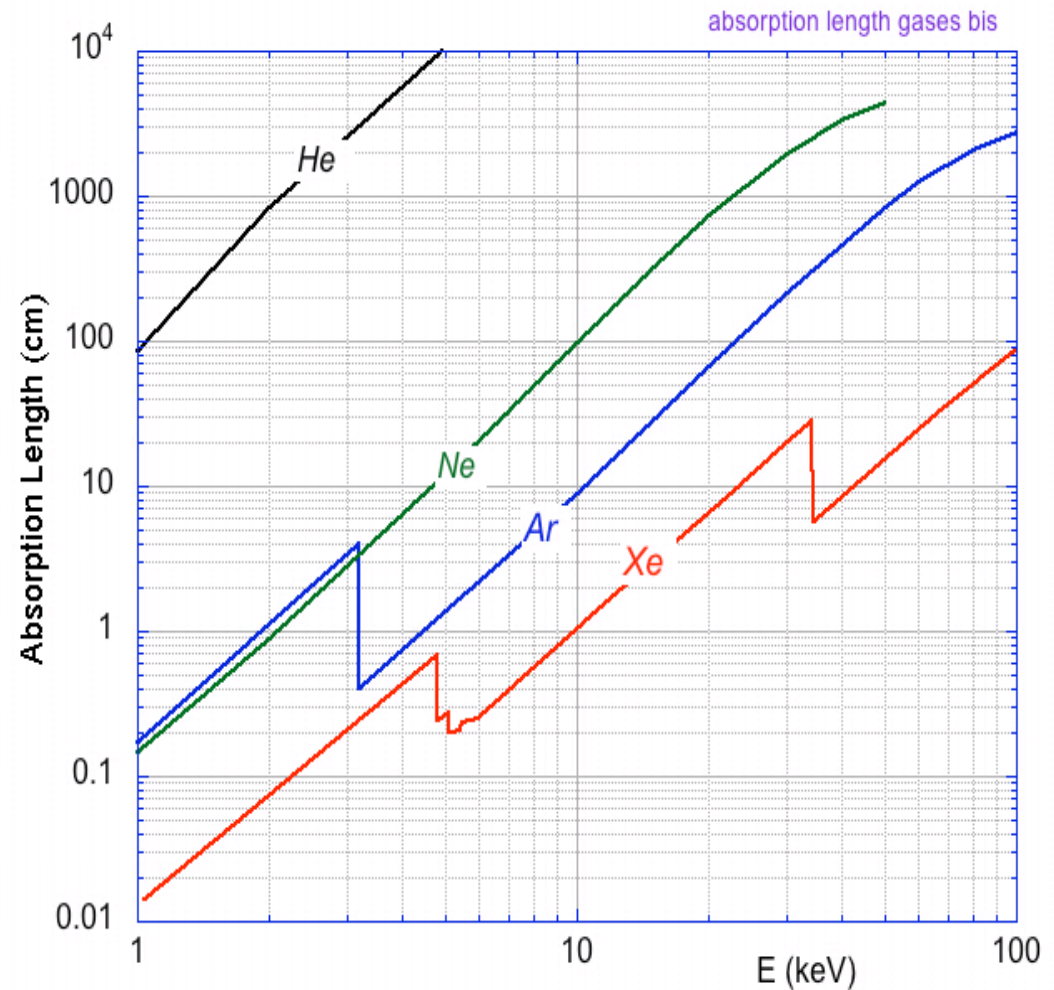
$$\lambda(\text{cm}) = \frac{1}{26.87 \sigma(\text{MBarns})}$$

The mass absorption coefficient
for molecules:

$$\mu_M = \frac{N_0}{M} \sum_i n_i \sigma_i$$

M: molecular weight

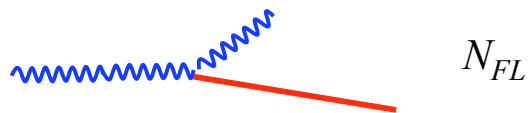
n_i σ_i : atoms, cross section type i



PHOTOELECTRIC FLUORESCENCE YIELD

An excited atom returns to the ground state with a cascade of internal transitions that can be radiative (with the emission of photons) or non-radiative:

RADIATIVE:

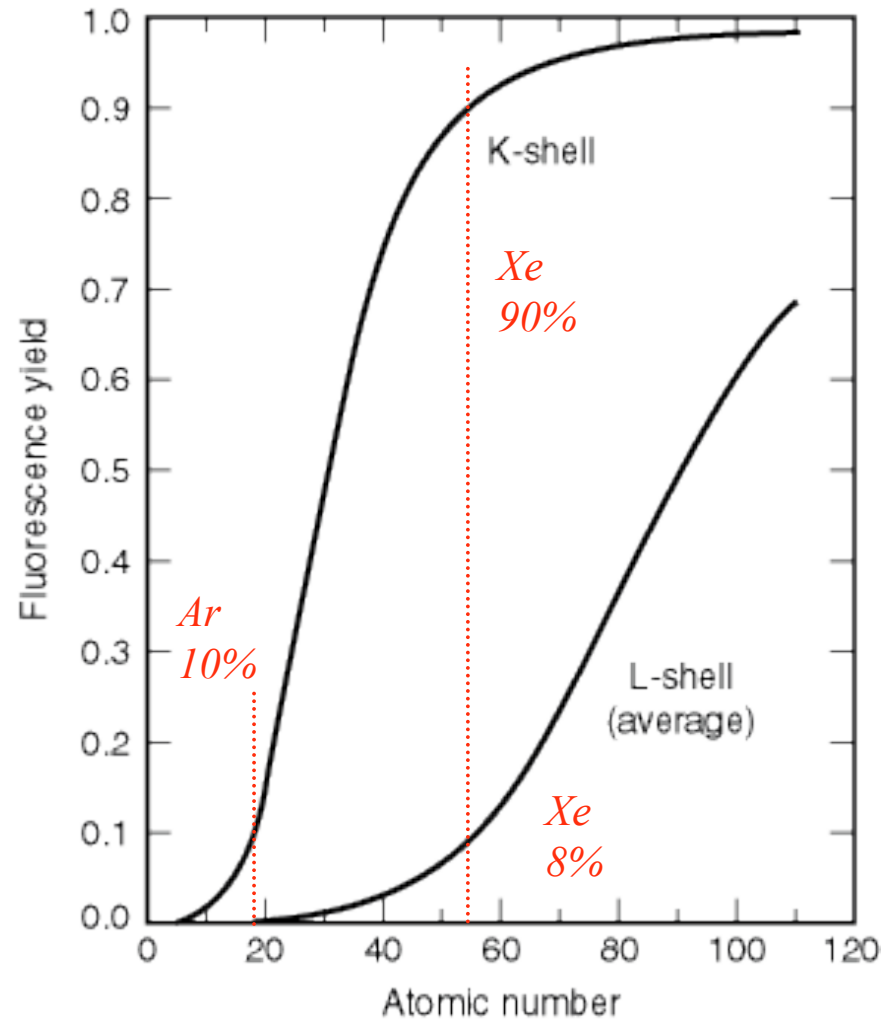


NON-RADIATIVE (AUGER):



The fluorescence yield is the ratio of radiative to total transitions, and increases with the atomic number:

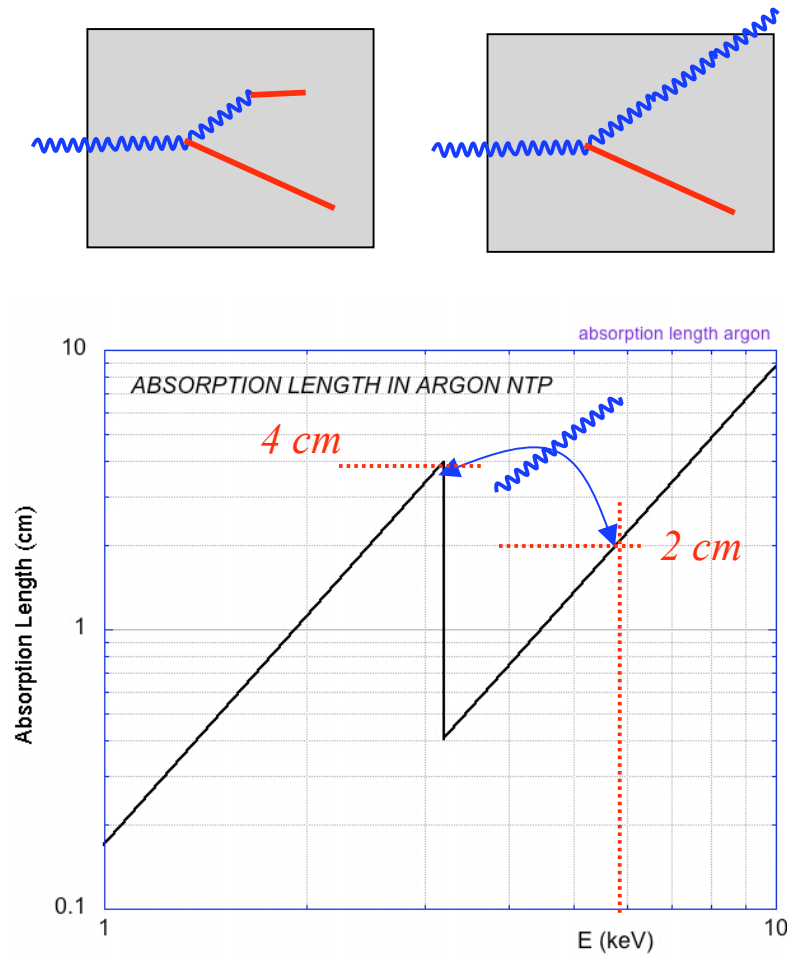
$$\text{FLUORESCENCE YIELD} = \frac{N_{FL}}{N_{FL} + N_{NR}}$$



M. O. Krause, J. Phys. Chem. Ref. Data 8 (1979) 307

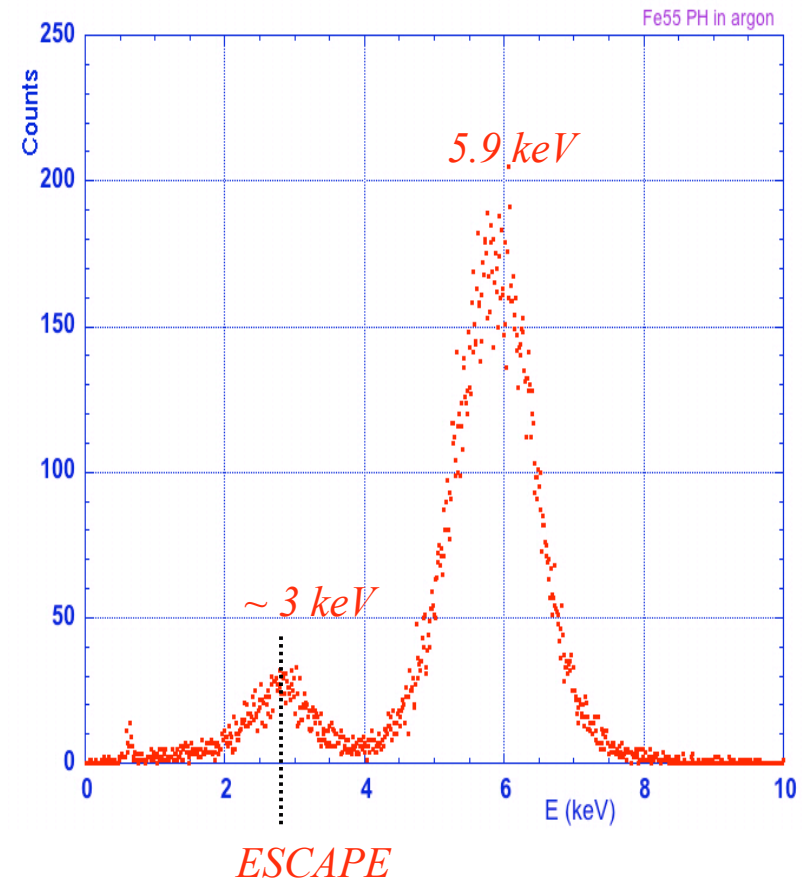
FLUORESCENCE PHOTONS FATE

Fluorescence photons can convert far from the primary interaction, or escape from the sensitive volume (escape peak):



X-RAY ABSORPTION SPECTRUM

^{55}Fe X-Rays (5.9 keV) in Argon:



COMPTON EFFECT

Scattering of the photon on a quasi-free electron of electronic shells

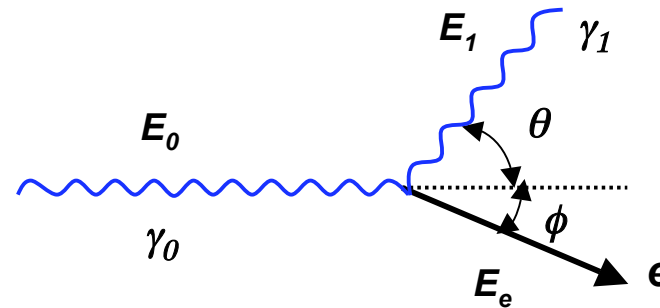
$$E_e = E_0 - E_1$$

$$\cos \theta = 1 - m_e c^2 \left(\frac{1}{E_1} - \frac{1}{E_0} \right)$$

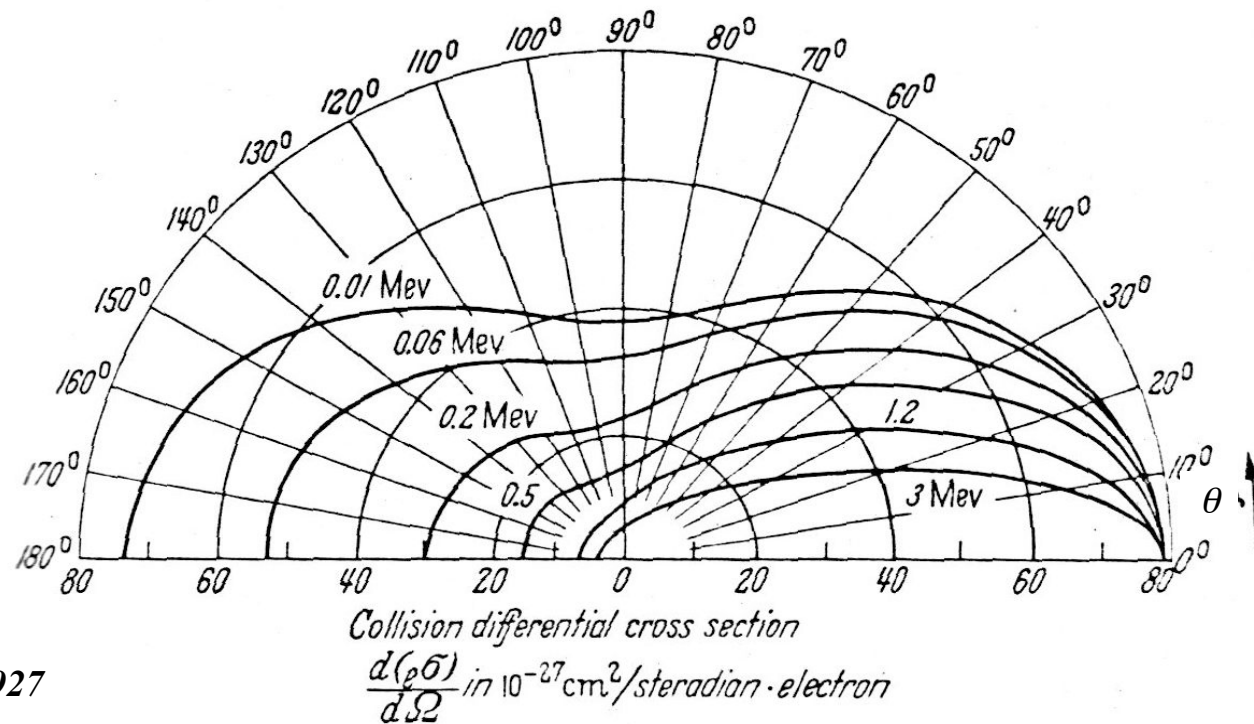
$$\cot \phi = \left(1 + \frac{E_0}{m_e c^2} \right) \tan \frac{\theta}{2}$$



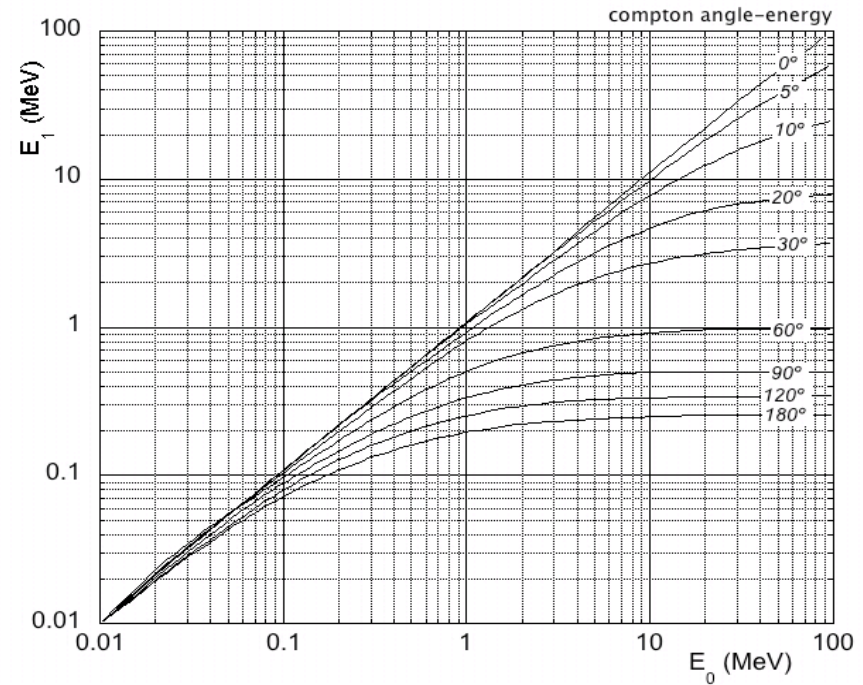
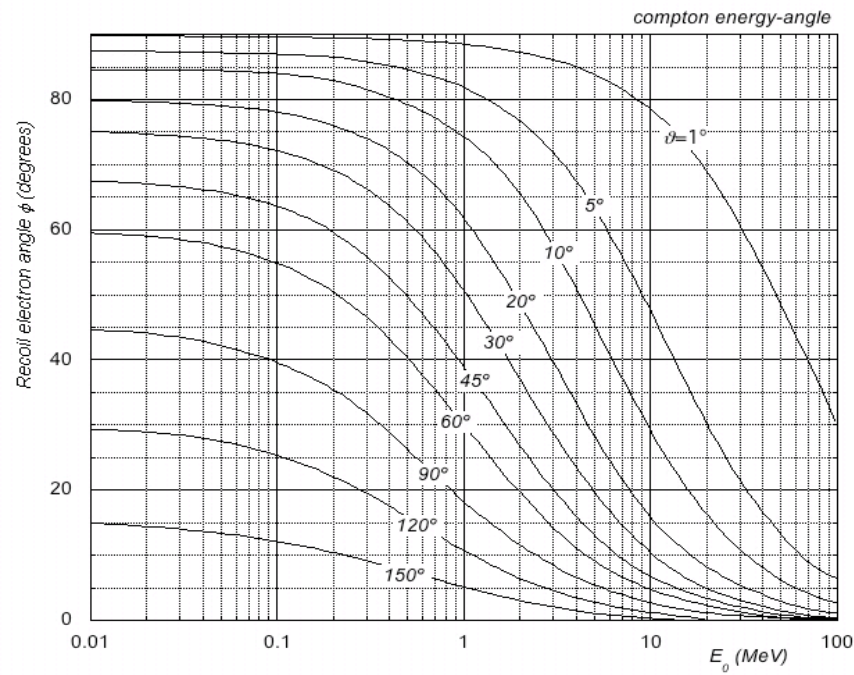
Arthur Holly Compton
Nobel Laureate in Physics 1927



DIFFERENTIAL CROSS SECTION FOR SCATTERING AT AN ANGLE θ FOR SEVERAL PHOTON ENERGIES:



COMPTON SCATTERING: ANGLE-ENERGY CORRELATIONS

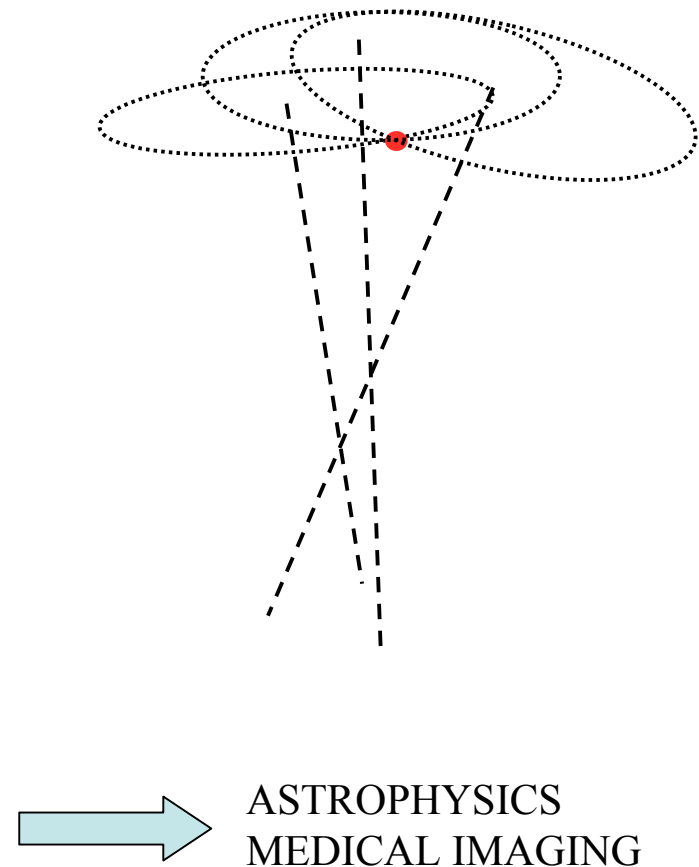
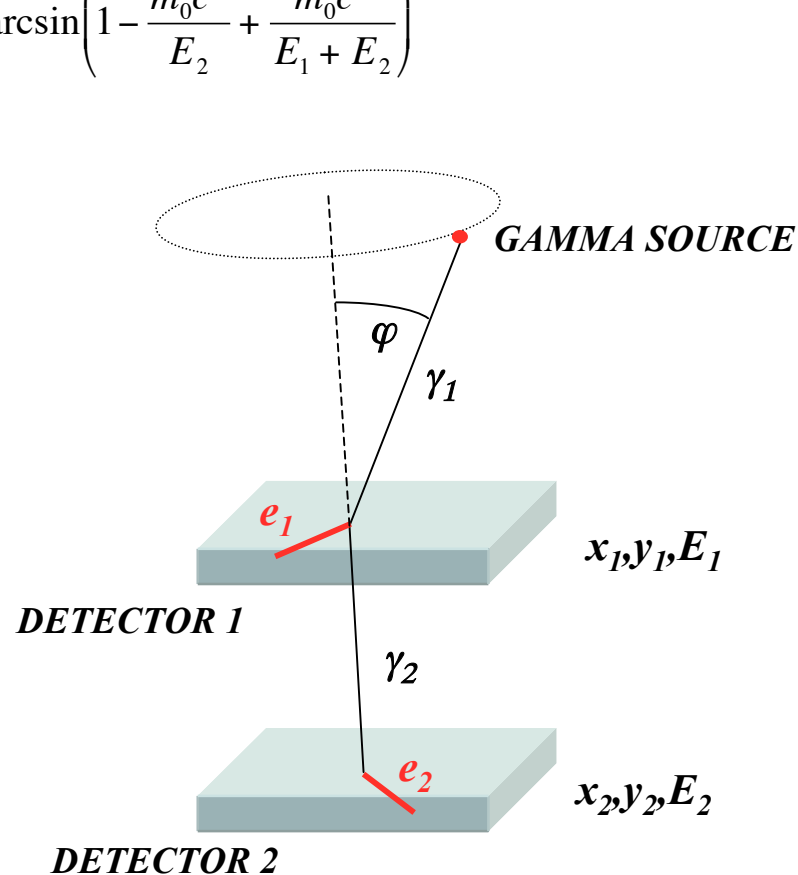


R. D. Evans, Compton Effect
Handbuch der Physik 34 p. 218 (Springer Verlag 1958)

DOUBLE COMPTON SCATTERING

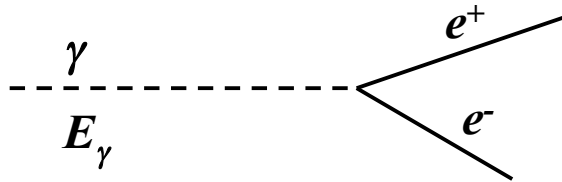
Measurement of recoil electrons energy and position in two cascades detectors allows to define a circle of origin for the source; intersection of many events provides the source position:

$$\varphi = \arcsin\left(1 - \frac{m_0 c^2}{E_2} + \frac{m_0 c^2}{E_1 + E_2}\right)$$

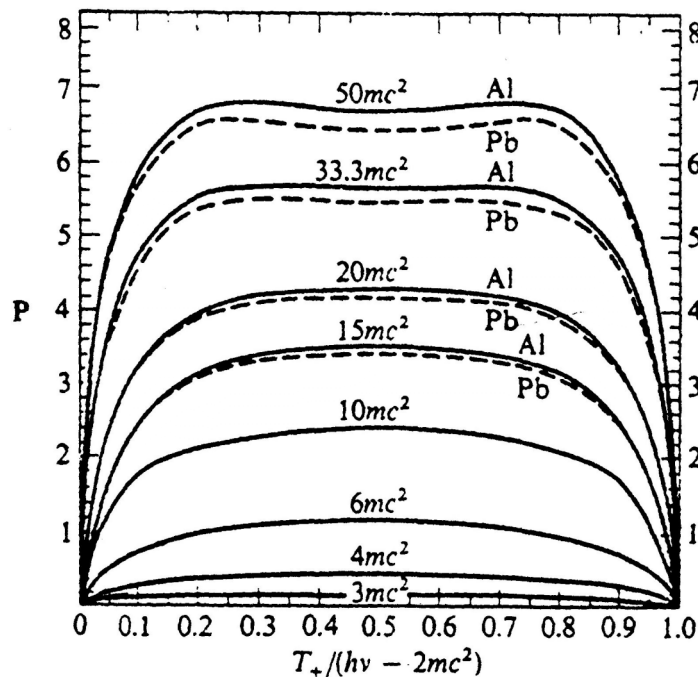


HIGH ENERGY: PAIR PRODUCTION

For $E_\gamma > 2 m_e$ the photon can create an electron-positron pair; the cross section increases very fast with energy.

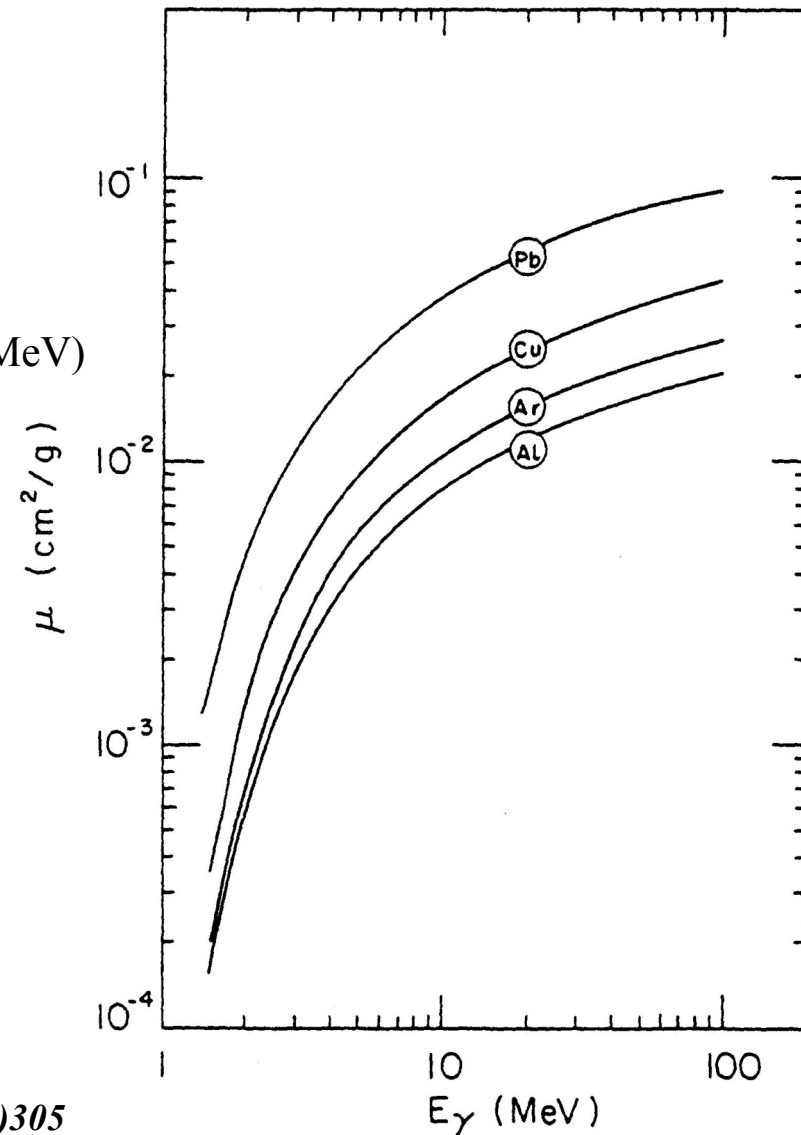


ENERGY SHARING BETWEEN e^+ and e^-
(Photon energy in terms of electron rest energy 0.511 MeV)

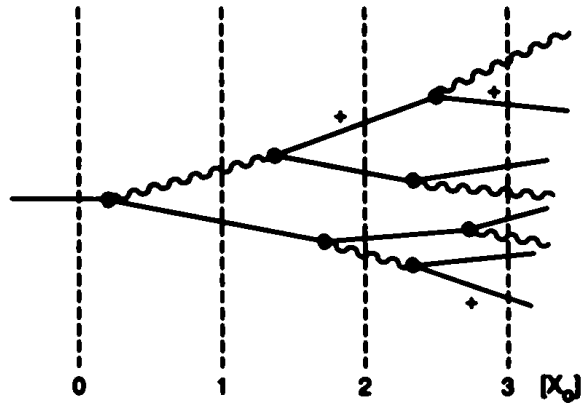


C.M. Davisson and R.D. Evans, Rev. Modern Phys. 20(1948)305

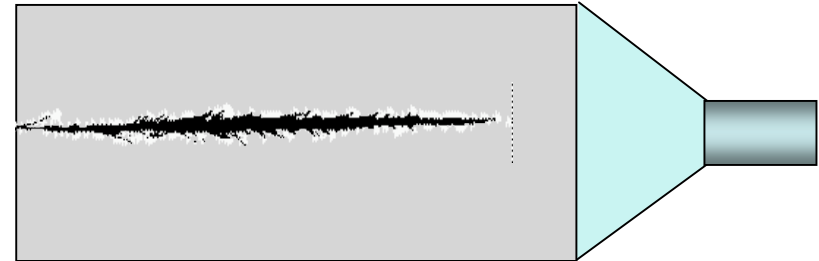
ABSORPTION COEFFICIENT:



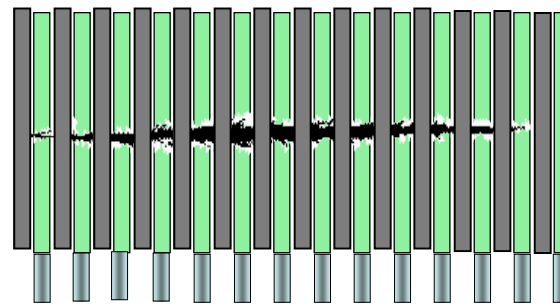
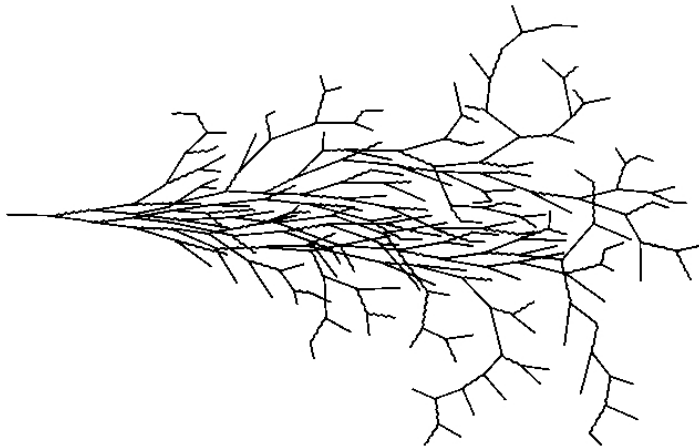
ELECTROMAGNETIC SHOWERS



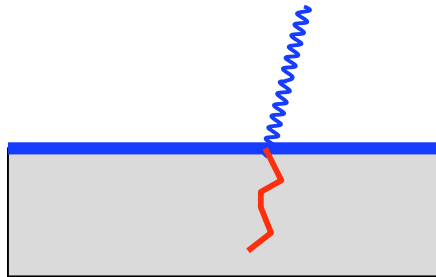
HOMOGENEOUS CALORIMETERS:



SAMPLING CALORIMETERS:



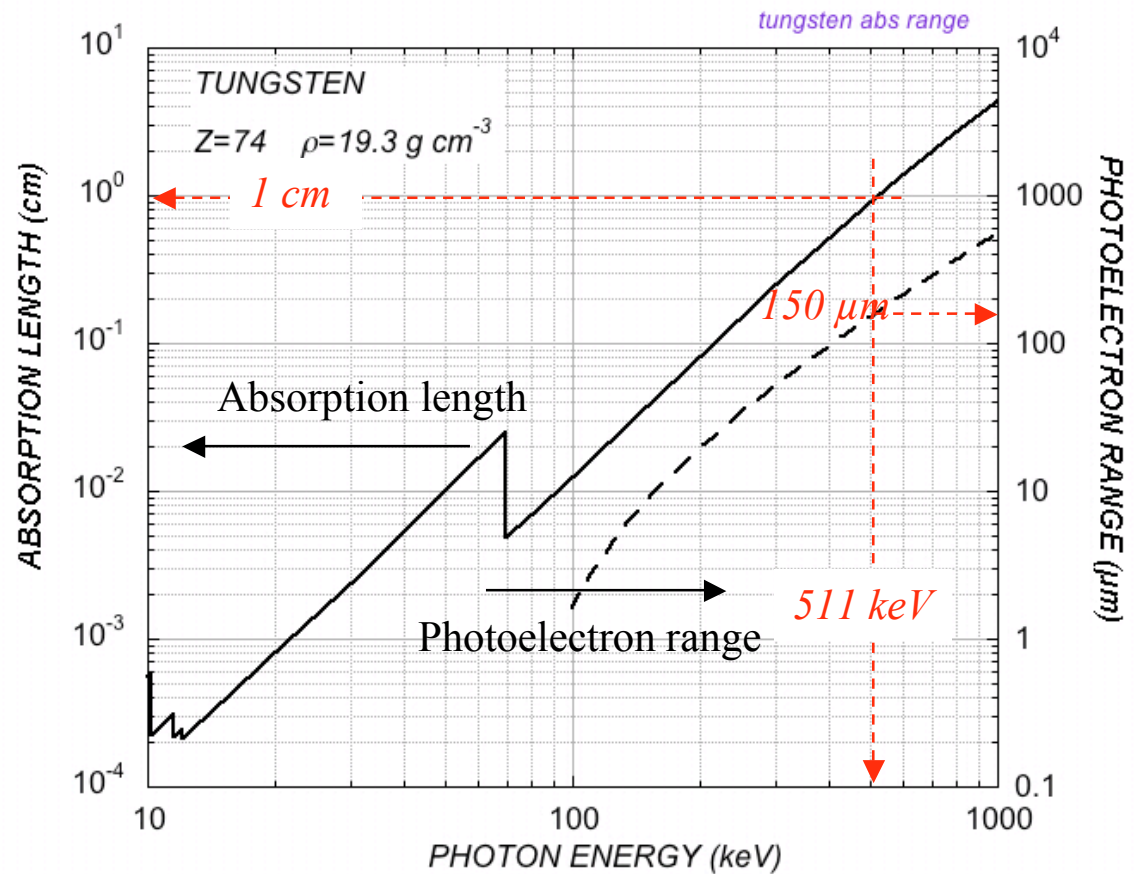
HARD X-RAYS: CONVERTERS AND DETECTION IN GASES



THICK FOIL:

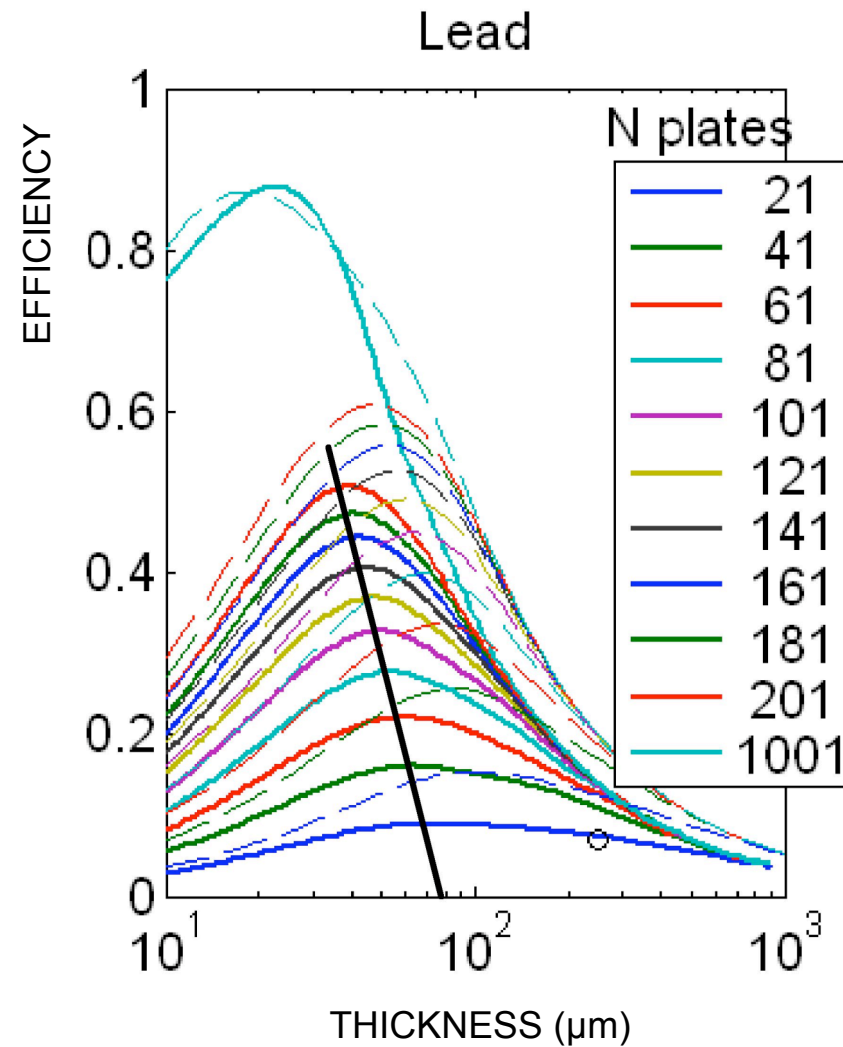
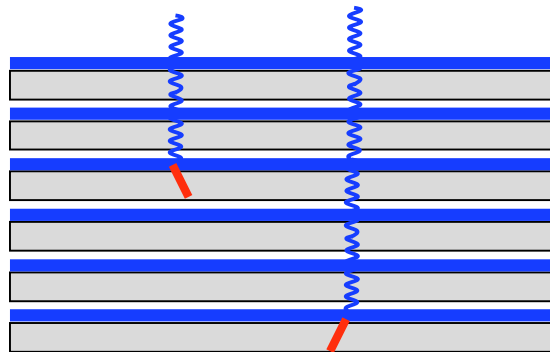
- HIGHER CONVERSION EFFICIENCY
- LOWER PHOTOELECTRON EXTRACTION EFFICIENCY

For 511 keV photons the 441 keV photoelectron (511-70) has a range in Tungsten of 150 μm . The optimum thickness of the converter is around 100 μm , $\sim 1/100$ of the absorption length, so the theoretical detections efficiency is $\sim 1\%$.



DETECTION AND LOCALIZATION OF 511 keV PHOTONS

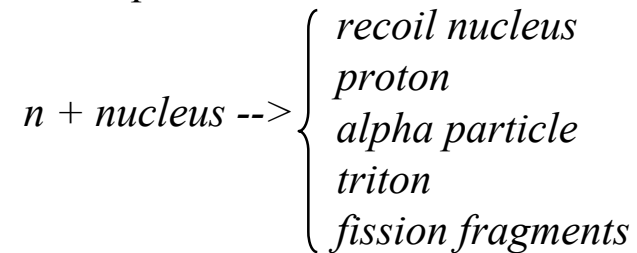
MULTILAYER CONVERTERS-
GAS DETECTORS



GEANT4 Calculation by P. Fonte (Imaging 2006)

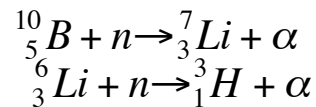
DETECTION OF NEUTRONS WITH GAS DETECTORS

Neutrons are detected through the products of their nuclear interaction with matter. Interaction cross sections depend on energy and material; possible reaction products are:

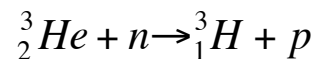


TYPES OF DETECTORS:

- With thin converter foil, exploiting the reactions:

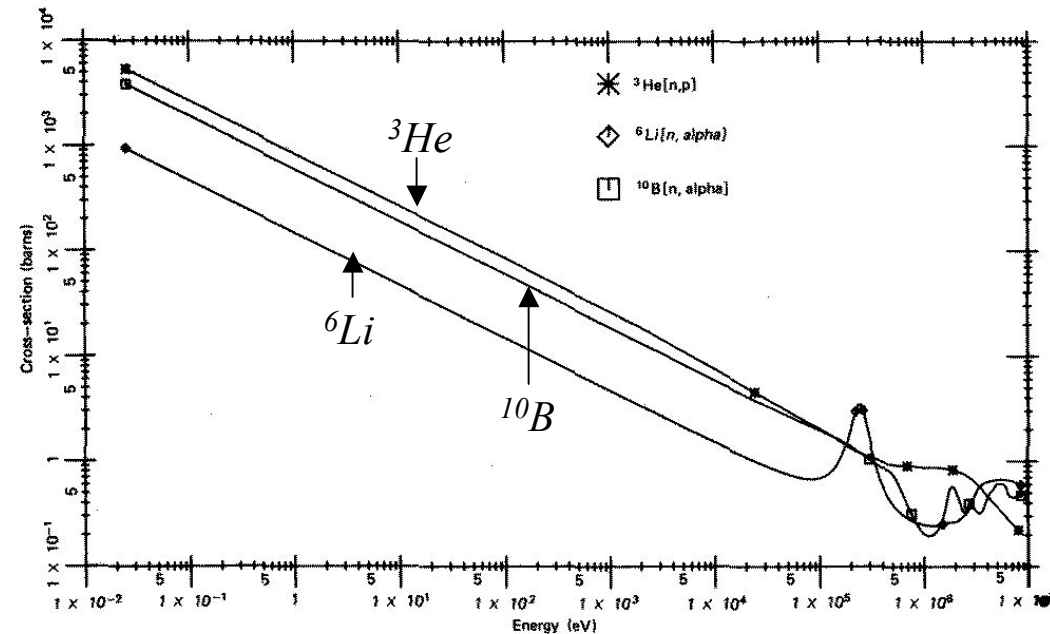


- With direct reaction on the gas (${}^3\text{He}$):



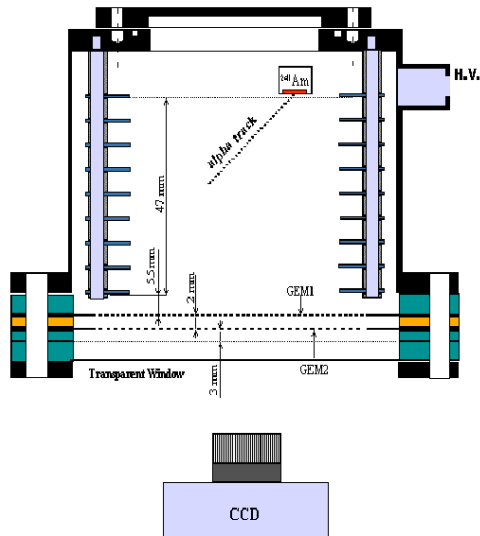
The charged prongs are then detected by their ionization in the medium.

NEUTRON CROSS SECTIONS:



*G. Knoll, Radiation Detection and Measurements
(Wiley, New York 2000)*

OPTICAL IMAGING CHAMBER FOR NEUTRON DETECTION



F.A.F. Fraga et al, Nucl. Instr. and Meth. A478 (2002) 357